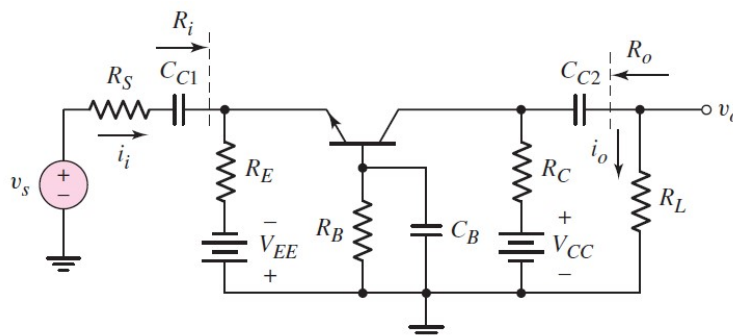


ECE322L -Homework 9 (100 points)
Assigned on Thursday, 04/09/2020-11 am
Due on Thursday, 04/23/2020-11 am

Consider the circuit below. The transistor parameters are: $\beta=120$, $V_{BE(on)}=0.7\text{ V}$, $V_A=\infty$. The circuit parameters are $V_{CC}=V_{EE}=3.3\text{ V}$, $R_S=500\ \Omega$, $R_L=6\text{ k}\Omega$, $R_B=100\text{ k}\Omega$, $R_E=12\text{ k}\Omega$, $R_C=12\text{ k}\Omega$.

- (a) Calculate the average power dissipated in the transistor and R_C , for $v_s=0$.
 (b) Determine the maximum undistorted signal power that can be delivered to R_L , and the resulting average power dissipated in the transistor and R_C .



$$(a) I_{BQ} = \frac{V_{EE} - V_{BE(on)}}{R_B - (1 + \beta)R_E} = \frac{3.3\text{ V} - 0.7\text{ V}}{100\text{ k}\Omega + (121)12\text{ k}\Omega} = 1.6753\mu\text{ A}$$

$$I_{CQ} = \beta I_{BQ} = 120 \times 1.6753\mu\text{ A} = 201.03\mu\text{ A}$$

$$V_{CC} - I_{CQ}R_C + I_{BQ}R_B - V_{BCQ} = 0 \rightarrow$$

$$V_{BCQ} = 3.3\text{ V} - (201.03\mu\text{ A})(12\text{ k}\Omega) + (1.6753\mu\text{ A})(100\text{ k}\Omega) = 1.0552\text{ V}$$

Average Power dissipated in the transistor

$$\overline{P_Q} = I_{CQ}V_{BCQ} = (201.03\mu\text{ A})(1.0552\text{ V}) = 212.12\mu\text{ W}$$

Average Power dissipated in R_C

$$\overline{P_{R_C}} = I_{CQ}^2 R_C = (201.03\mu\text{ A})^2 (12\text{ k}\Omega) = 484.96\mu\text{ W}$$

$$(b) \overline{P_{R_L}} = \frac{V_{out}^2}{R_L} = \frac{(I_C (R_C \parallel R_L))^2}{R_L} = 53.885\mu\text{ W}$$

$$\overline{P_Q} = I_{CQ}V_{BCQ} - \frac{1}{2}I_C^2 (R_C \parallel R_L) = 131.29\mu\text{ W}$$

$$\overline{P_{R_C}} = I_{CQ}^2 R_C + \frac{1}{2}I_C^2 R_C = 606.2\mu\text{ W}$$